

Single Phase Bridge (Power Modules), 25 A/35 A



D-34

FEATURES

- Universal, 3 way terminals: push-on, wrap around or solder
- High thermal conductivity package, electrically insulated case
- Center hole fixing
- Excellent power/volume ratio
- Nickel plated terminals solderable using lead (Pb)-free solder; solder alloy Sn/Ag/Cu (SAC305); solder temperature 260 to 275 °C
- UL E300359 approved 
- RoHS compliant
- Designed and qualified for industrial and consumer level



RoHS
COMPLIANT

PRODUCT SUMMARY

I_o	25 A/35 A
-------	-----------

DESCRIPTION

A range of extremely compact, encapsulated single phase bridge rectifiers offering efficient and reliable operation. They are intended for use in general purpose and instrumentation applications.

MAJOR RATINGS AND CHARACTERISTICS

SYMBOL	CHARACTERISTICS	26MB-A	36MB-A	UNITS
I_o		25	35	A
	T_c	70	55	°C
I_{FSM}	50 Hz	400	475	A
	60 Hz	420	500	
I^2t	50 Hz	790	1130	A ² s
	60 Hz	725	1030	
V_{RRM}	Range	1400 to 1600	1400 to 1600	V
T_J		- 55 to 150	- 55 to 150	°C

ELECTRICAL SPECIFICATIONS

VOLTAGE RATINGS

TYPE NUMBER	VOLTAGE CODE	V_{RRM} , MAXIMUM REPETITIVE PEAK REVERSE VOLTAGE V	V_{RSM} , MAXIMUM NON-REPETITIVE PEAK REVERSE VOLTAGE V	I_{RRM} MAXIMUM AT T_J MAXIMUM mA
26MB..A	140	1400	1500	2
36MB..A	160	1600	1700	

FORWARD CONDUCTION							
PARAMETER	SYMBOL	TEST CONDITIONS			26MB-A	36MB-A	UNITS
Maximum DC output current at case temperature	I _O	Resistive or inductive load			25	35	A
		Capacitive load			20	28	
					65	60	°C
Maximum peak, one cycle non-repetitive forward current	I _{FSM}	t = 10 ms	No voltage reapplied	Initial T _J = T _J maximum	400	475	A
		t = 8.3 ms			420	500	
		t = 10 ms	100 % V _{RRM} reapplied		335	400	
		t = 8.3 ms			350	420	
Maximum I ² t for fusing	I ² t	t = 10 ms	No voltage reapplied		790	1130	A ² s
		t = 8.3 ms			725	1030	
		t = 10 ms	100 % V _{RRM} reapplied		560	800	
		t = 8.3 ms			512	730	
Maximum I ² √t for fusing	I ² √t	I ² t for time t _x = I ² √t x √t _x ; 0.1 ≤ t _x ≤ 10 ms, V _{RRM} = 0 V			5.6	11.3	kA ² √s
Low level of threshold voltage	V _{F(TO)1}	(16.7 % x π x I _{F(AV)}) < I < π x I _{F(AV)}), T _J maximum			0.70	0.74	V
High level of threshold voltage	V _{F(TO)2}	(I > π x I _{F(AV)}), T _J maximum			0.75	0.79	
Low level forward slope resistance	r _{t1}	(16.7 % x π x I _{F(AV)}) < I < π x I _{F(AV)}), T _J maximum			7.0	5.5	mΩ
High level forward slope resistance	r _{t2}	(I > π x I _{F(AV)}), T _J maximum			6.4	5.2	
Maximum forward voltage drop	V _{FM}	T _J = 25 °C, I _{FM} = 40 Apk (26MB)		t _p = 400 μs	1.25	1.3	V
		T _J = 25 °C, I _{FM} = 55 Apk (36MB)					
Maximum DC reverse current per diode	I _{RRM}	T _J = 25 °C, at V _{RRM}			10	10	μA
RMS isolation voltage base plate	V _{ISOL}	f = 50 Hz, t = 1 s			2700	2700	V

THERMAL AND MECHANICAL SPECIFICATIONS					
PARAMETER	SYMBOL	TEST CONDITIONS	26MB-A	36MB-A	UNITS
Junction and storage temperature range	T _J , T _{Stg}		- 55 to 150		°C
Maximum thermal resistance, junction to case per bridge	R _{thJC}		1.7	1.35	K/W
Maximum thermal resistance, case to heatsink	R _{thCS}	Mounting surface, smooth, flat and greased	0.2		
Mounting torque ± 10 %		Bridge to heatsink	2.0		Nm
Approximate weight			20		g



MB High Voltage Series

Single Phase Bridge
(Power Modules), 25 A/35 A

Vishay High Power Products

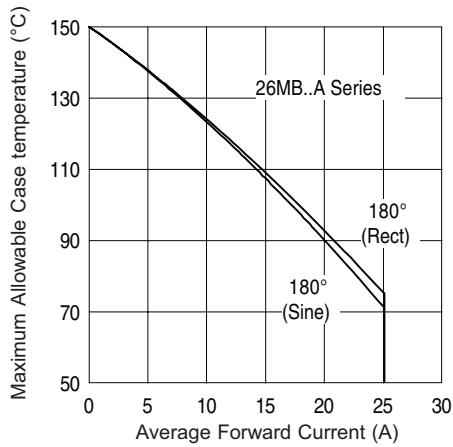


Fig. 1 - Current Ratings Characteristics

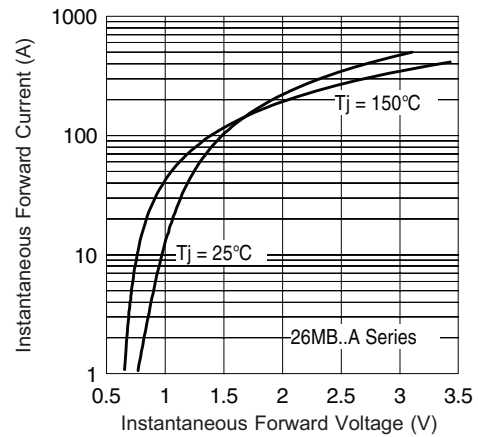


Fig. 2 - Forward Voltage Drop Characteristics

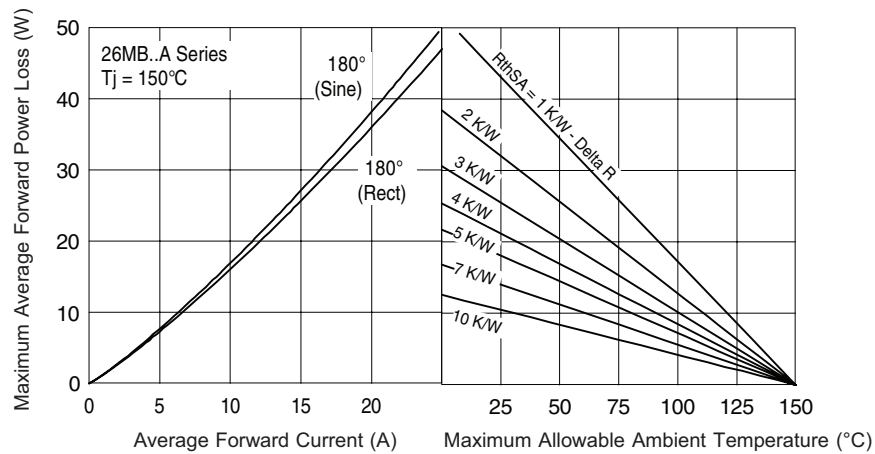


Fig. 3 - Total Power Loss Characteristics

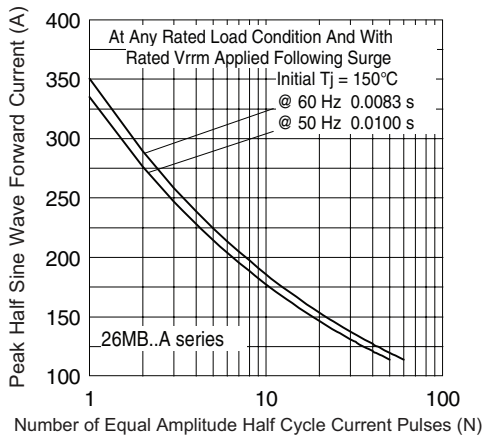


Fig. 4 - Maximum Non-Repetitive Surge Current

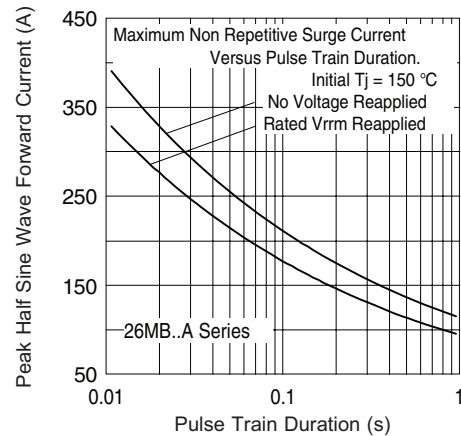


Fig. 5 - Maximum Non-Repetitive Surge Current

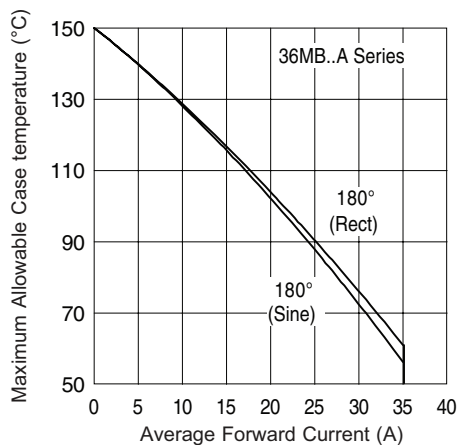


Fig. 6 - Current Ratings Characteristics

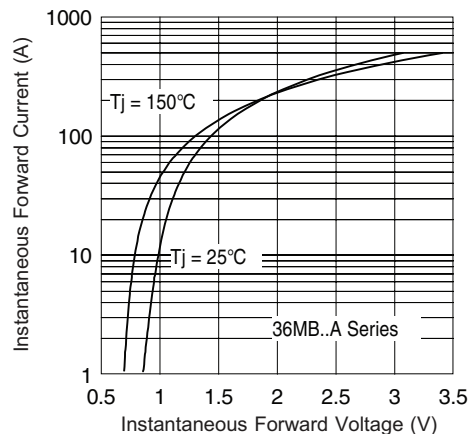


Fig. 7 - Forward Voltage Drop Characteristics

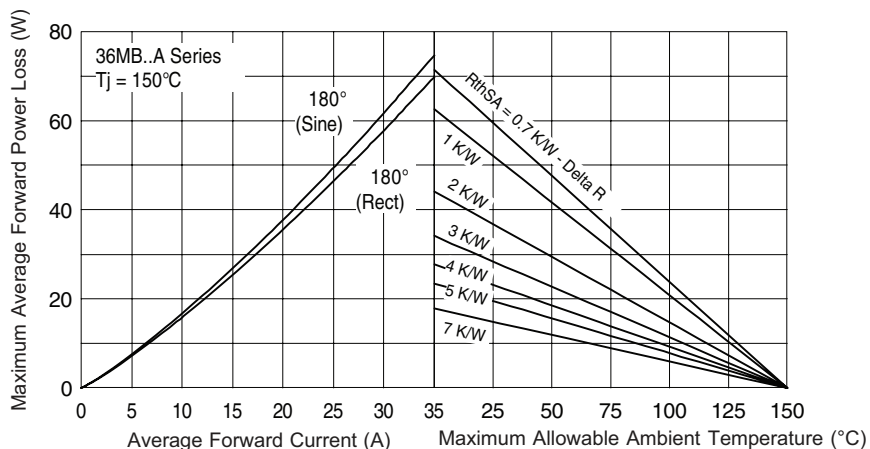


Fig. 8 - Total Power Loss Characteristics

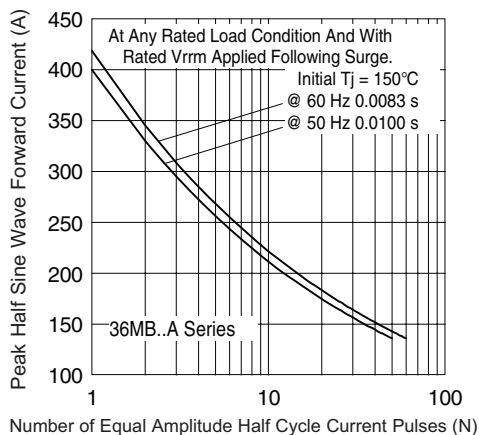


Fig. 9 - Maximum Non-Repetitive Surge Current

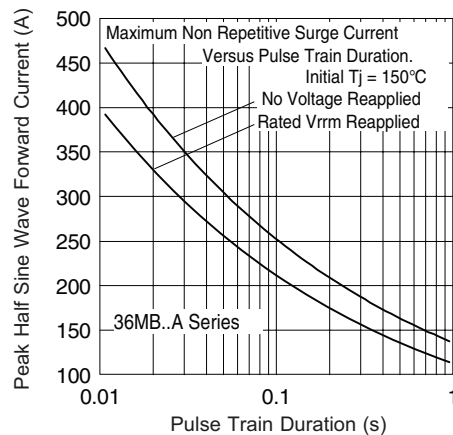


Fig. 10 - Maximum Non-Repetitive Surge Current

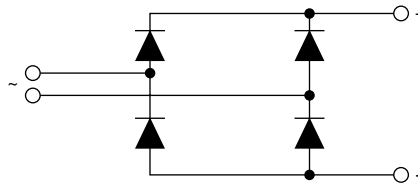


ORDERING INFORMATION TABLE

Device code	36	MB	160	A
	1	2	3	4
1	- Current rating code			
2	- Circuit configuration:			
	MB = Single phase european coding			
3	- Voltage code x 10 = V_{RRM}			
4	- Diode bridge rectifier:			
	A = 26 MB, 36MB series			

26 = 25 A (average)
36 = 35 A (average)

CIRCUIT CONFIGURATION



LINKS TO RELATED DOCUMENTS	
Dimensions	http://www.vishay.com/doc?95326



Disclaimer

All product specifications and data are subject to change without notice.

Vishay Intertechnology, Inc., its affiliates, agents, and employees, and all persons acting on its or their behalf (collectively, "Vishay"), disclaim any and all liability for any errors, inaccuracies or incompleteness contained herein or in any other disclosure relating to any product.

Vishay disclaims any and all liability arising out of the use or application of any product described herein or of any information provided herein to the maximum extent permitted by law. The product specifications do not expand or otherwise modify Vishay's terms and conditions of purchase, including but not limited to the warranty expressed therein, which apply to these products.

No license, express or implied, by estoppel or otherwise, to any intellectual property rights is granted by this document or by any conduct of Vishay.

The products shown herein are not designed for use in medical, life-saving, or life-sustaining applications unless otherwise expressly indicated. Customers using or selling Vishay products not expressly indicated for use in such applications do so entirely at their own risk and agree to fully indemnify Vishay for any damages arising or resulting from such use or sale. Please contact authorized Vishay personnel to obtain written terms and conditions regarding products designed for such applications.

Product names and markings noted herein may be trademarks of their respective owners.